


SANYO Semiconductors
DATA SHEET

Bi-CMOS IC
LV23002M — For Radio Cassette and Mini Component System
1-chip Tuner IC Incorporating PLL

Overview

The LV23002M is a one-chip tuner IC incorporating PLL for radio cassette and mini component system.

Features

- AM
- FM-FE
- FM-IF
- MPX
- PLL

Specifications

Maximum Ratings at Ta = 25°C

| Parameter | Symbol | Conditions | Ratings | Unit |
|-----------------------------|----------------------|---|----------------------|------|
| Maximum supply voltage | V _{CC} max | V _{CC} | 7.0 | V |
| | V _{DD} max | V _{DD} | 5.0 | V |
| Maximum input voltage | V _{IN1} max | CE, DI, CL | 5.0 | V |
| | V _{IN2} max | XIN | V _{DD} +0.3 | V |
| Maximum output voltage | V _{O1} max | DO | 6.0 | V |
| | V _{O2} max | XOUT, PD | V _{DD} +0.3 | V |
| | V _{O3} max | BO1, BO2, AOUT | 12.0 | V |
| Allowable power dissipation | P _d max | Ta≤70°C Mounted on a glass epoxy board. Board size : 114.3 mm×76.1mm = 1.6mm | 400 | mW |
| Operating temperature | T _{op} r | | -20 to +70 | °C |
| Storage temperature | T _{stg} | | -40 to +125 | °C |

Note : This product should be handled with care because the resistance of one pin against electrostatic discharge damage is low.

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Operating Condition at Ta = 25°C

| Parameter | Symbol | Conditions | Ratings | Unit |
|--------------------------------|--------------------|------------|------------|------|
| Recommended supply voltage | V _{CC} | | 5.0 | V |
| | V _{DD} | | 3.0 | V |
| Operating supply voltage range | V _{CC} op | | 4.0 to 6.0 | V |
| | V _{DD} op | | 2.5 to 3.6 | V |

Note : Use the product with the supply voltage applied to V_{CC} and V_{DD}.

PLL block Allowable Operating Range at Ta = -20 to +70°C, V_{SS} = 0V

| Parameter | Symbol | Conditions | Ratings | | | Unit |
|--------------------------|------------------|-----------------------------------|--------------------|-----|--------------------|------|
| | | | min | typ | max | |
| Supply voltage | V _{DD} | | 2.5 | | 3.6 | V |
| Input high level voltage | V _{IH} | CE, CL, DI | 0.7V _{DD} | | 5.0 | V |
| Input low level voltage | V _{IL} | CE, CL, DI | 0 | | 0.3V _{DD} | V |
| Output voltage | V _{O1} | DO | 0 | | 6.0 | V |
| | V _{O2} | BO1, BO2, AOUT | 0 | | 10 | V |
| Operating frequency | f _{IN1} | XIN ; V _{IN1} | | 75 | | kHz |
| | f _{IN2} | FMIN ; V _{IN2} | 10 | | 160 | MHz |
| | f _{IN3} | AMIN (SNS = 1) ; V _{IN3} | 2 | | 40 | MHz |
| | f _{IN4} | AMIN (SNS = 0) ; V _{IN4} | 0.5 | | 10 | MHz |

Note : Due attention must be paid on leak because the XIN pin has an extremely high input impedance.

Operating Characteristics at Ta = 25°C, V_{CC} = 5.0V, V_{DD} = 3.0V, See the specified circuit.

| Parameter | Symbol | Conditions | Ratings | | | Unit |
|--|----------------|--|---------|-----|------|--------------------------|
| | | | min | typ | max | |
| [FM-FE characteristics] : fc = 98MHz, fm = 1kHz, 22.5kHzdev. | | | | | | |
| 3dB sensitivity | 3dB LS | 60dB _μ V EMF, 30%mod output reference, -3dB input | | 3 | | dB _μ V EMF |
| Actual sensitivity | QS | S/N = Input at S/N = 30dB | | 10 | | dB _μ V EMF |
| [FM-IF monaural characteristics] : fc = 10.7MHz, fm = 1kHz, 75kHzdev. | | | | | | |
| Demodulation output | V _O | 100dB _μ V, 12pin output | 210 | 330 | 420 | mVrms |
| Channel balance | CB | 100dB _μ V, 13pin output /12pin output | -1.5 | 0 | +1.5 | dB |
| Signal-to-noise ratio | S/N | 100dB _μ V, 12pin output | 68 | 75 | | dB |
| Total harmonic distortion (Monaural) | THD | 100dB _μ V, 12pin output | | 0.3 | 1.5 | % |
| 3dB sensitivity | 3dB LS | V _O reference, Input level at which V _O reference is -3dB. | | 38 | 44 | dB _μ V |
| IF count sensitivity | IF-C3 | SDC0 = 1, SDC1 = 0, 18pin(DO) output | 45 | 51 | 61 | dB _μ V |
| Mute attenuation | Mute-Att | 100dB _μ V, 12pin output | | 68 | | dB |
| [FM-IF stereo characteristics] : fc = 10.7MHz, fm = 1kHz, L+R = 90%, Pilot = 10%, V _{IN} = 100dB _μ V | | | | | | |
| Separation | SEP | L-mod, 12pin output /13pin output | 28 | 40 | | dB |
| Total harmonic distortion (Main) | THD | Main-mod, 12pin output | | 0.5 | 1.5 | % |
| Stereo ON sensitivity | ST-ON | Stereo operation ON at Pilot = 5.5% Stereo not ON at Pilot = 0.6% | | | | |
| Cap challenge | CR | Stereo ON at fm = 18.6 kHz and 10% modulation fm = 19.4kHz, Stereo ON at fm = 19.4 kHz and 10% modulation | | | | |

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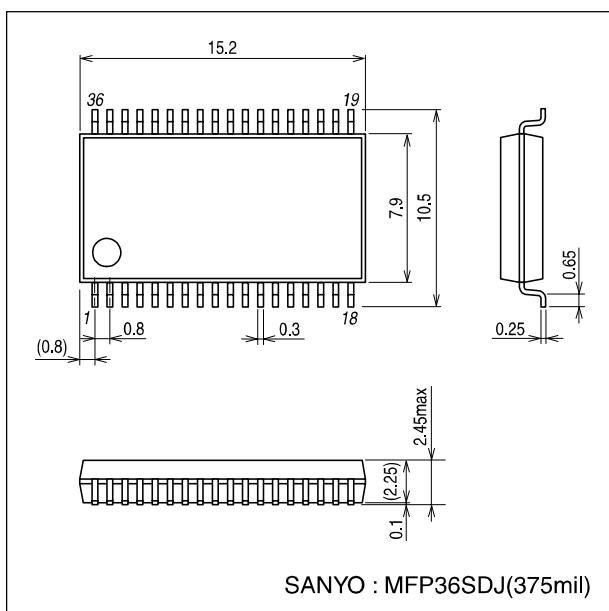
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| Parameter | Symbol | Conditions | Ratings | | | Unit |
|---|------------------|--|----------------------|--------------------|------|------------|
| | | | min | typ | max | |
| [AM characteristics] : fc = 1000kHz, fm = 1kHz, 30%mod | | | | | | |
| Detection output 1 | V _{O1} | 23dB μ V, 12pin output | 20 | 40 | 80 | mVrms |
| Detection output 2 | V _{O2} | 80dB μ V, 12pin output | 60 | 110 | 160 | mVrms |
| Signal-to-noise ratio 1 | S/N1 | 23dB μ V, 12pin output | 15 | 20 | | dB |
| Signal-to-noise ratio 2 | S/N2 | 80dB μ V, 12pin output | 47 | 54 | | dB |
| Total harmonic distortion | THD | 80dB μ V, 12pin output | | | 1.2 | 3.0 |
| IF count sensitivity | IF-C | 18pin(DO) output | 16 | 26 | 36 | dB μ V |
| Low-range attenuation | LOW-CUT | V _{O2} reference, Pin 12 output at fm = 100Hz | 5 | 8 | 11 | dB |
| [Current dissipation] | | | | | | |
| Current dissipation | ICCFM | No input in FM mode | 20 | 30 | 40 | mA |
| | ICCAM | No input in AM mode | 10 | 20 | 30 | |
| | I _{DD} | f _r = 83MHz, X'tal = 75kHz, No input to tuner | 1 | 2 | 5 | |
| [PLL characteristics] | | | | | | |
| Internal return resistance | R _f | XIN | | 8 | | M Ω |
| Built-in output resistance | R _d | XOUT | | 250 | | k Ω |
| Hysteresis width | VHIS | CE, CL, DI | | 0.1V _{DD} | | V |
| Output high level voltage | V _{OH} | PD ; I _O = -1mA | V _{DD} -1.0 | | | V |
| Output low level voltage | V _{OL1} | PD ; I _O = 1mA | | | 1.0 | V |
| | V _{OL2} | BO1, BO2 ; I _O = 1mA | | | 0.25 | V |
| | | BO1, BO2 ; I _O = 5mA | | | 1.25 | V |
| | V _{OL3} | DO ; I _O = 1mA | | | 0.25 | V |
| Input high level current | V _{OL4} | AOUT ; I _O = 1mA, AIN = 2.0V | | | 0.5 | V |
| | I _{IH1} | CE, CL, DI ; V _I = 6.0V | | | 5.0 | μ A |
| | I _{IH2} | XIN ; V _I = V _{DD} | 0.16 | | 0.9 | μ A |
| | I _{IH3} | AIN ; V _I = 6.0V | | | 200 | nA |
| Input low level current | I _{IL1} | CE, CL, DI ; V _I = 0V | | | 5.0 | μ A |
| | I _{IL2} | XIN ; V _I = 0V | 0.16 | | 0.9 | μ A |
| | I _{IL3} | AIN ; V _I = 0V | | | 200 | nA |
| Output off-leak current | IOFF1 | BO1, AOUT, BO2 ; V _O = 10V | | | 5.0 | μ A |
| | IOFF2 | DO ; V _O = 6.0V | | | 5.0 | μ A |
| "H" level 3-state off-leak current | IOFFH | PD ; V _O = 6.0V | | 0.01 | 200 | nA |
| "L" level 3-state off-leak current | IOFFL | PD ; V _O = 0V | | 0.01 | 200 | nA |

Package Dimensions

unit : mm

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